

PWM Controlled Step-Up DC/DC Converters

GreenOperation-Compatible

GENERAL DESCRIPTION

The XC6371/XC6372 series is a group of PWM controlled and PWM/PFM controlled step-up DC/DC converters. The built-in 1.4 switching transistor type enables a step-up circuit to be configured using only three components, a coil, a diode, and a capacitor.

Output voltage can be selectable in the range from 2.0V to 7.0V in increments of 0.01V (accuracy: $\pm 2.5\%$). Oscillation frequency is also selectable from 50kHz, 100kHz, and 180kHz (accuracy: $\pm 15\%$) for the XC6371 and the XC6372 series. Soft-start time is internally set and offers protection against in-rush currents when the power is switched on and prevents voltage overshoot. Packages with CE (chip enable) pin are also available which can reduce the IC power consumption during during stand-by mode.

The XC6371 series is the standard PWM controlled products. The control of the XC6372 series switches from PWM to PFM control during light loads when automatically switching is selected and the series is highly efficient from light loads to large output currents.

APPLICATIONS

Cellular phones, Pagers

Palmtops

Cameras, Video recorders

Portable products

FEATURES

Operation Start Voltage Range : 0.9V~10V

Output Voltage Range : 2.0V~7.0V (0.1V increments)

Highly Accurate : $\pm 2.5\%$ Oscillation Frequency : 50kHz, 100kHz, 180kHz ($\pm 15\%$)Maximum Output Currents : 100mA(TYP.) @ $V_{IN}=3.0V$, $V_{OUT}=5.0V$ *Highly Efficient : 85%(TYP.) @ $V_{IN}=3.0V$, $V_{OUT}=5.0V$ *

Built-in switching transistor.

CE pin type (XC6371C, XC6372C)

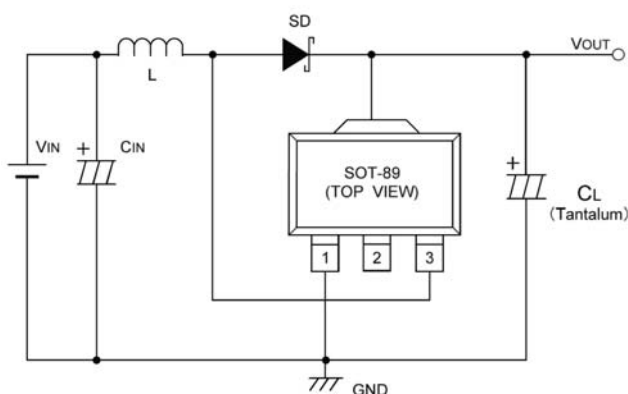
Phase compensation and soft start-up circuits built-in

CMOS Low Power Consumption

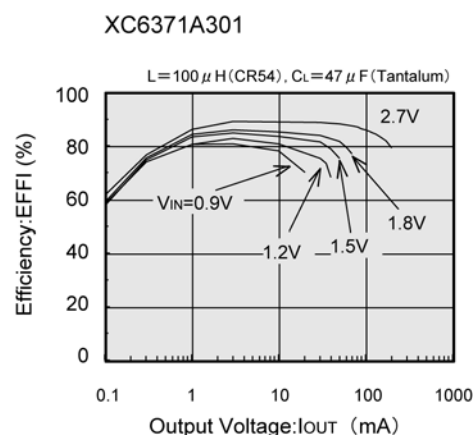
Packages : SOT-89, SOT-89-5, USP-6B

* Performance depends on external components and PCB layout.

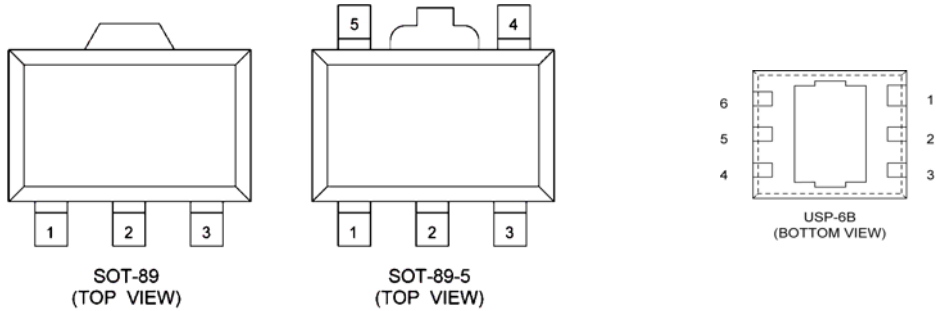
TYPICAL APPLICATION CIRCUIT



TYPICAL PERFORMANCE CHARACTERISTICS



PIN CONFIGURATION



*The dissipation pad for the USP-6B package should be solder-plated in recommended mount pattern and metal masking so as to enhance mounting strength and heat release. If the pad needs to be connected to other pins, it should be connected to the pin No.1.

PIN ASSIGNMENT

XC6371/XC6372A

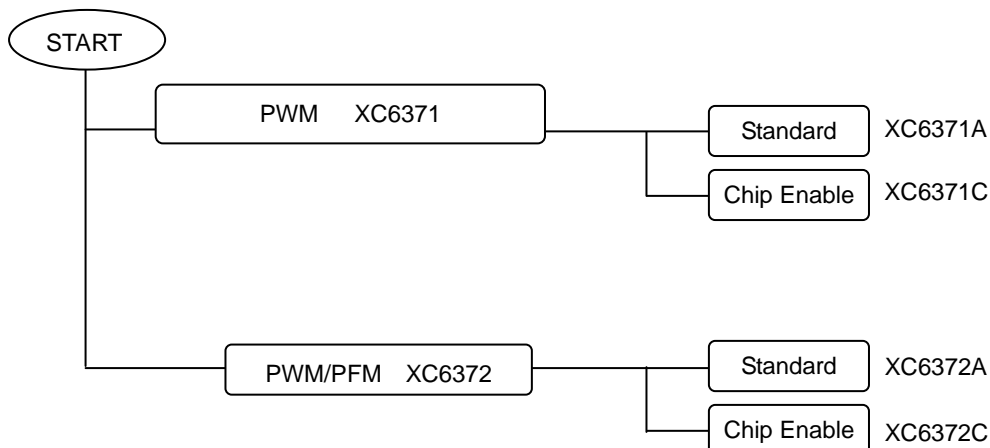
PIN NUMBER		PIN NAME	FUNCTION
SOT-89	USP-6B		
1	6	VSS	Ground
2	1	VOUT	Output Voltage Monitor/IC Internal Power Supply
3	4	Lx	Switch
-	2, 3, 5	NC	No Connection

XC6371/XC6372C

PIN NUMBER		PIN NAME	FUNCTION
SOT-89-5	USP-6B		
5	6	VSS	Ground
2	1	VOUT	Output Voltage Monitor/IC Internal Power Supply
4	4	Lx	Switch
3	3	CE	Chip Enable
1	2, 5	NC	No Connection

PRODUCT CLASSIFICATION

Selection Guide



Ordering Information

XC6371 : PWM controlled

XC6372 : PWM/PFM switching control

DESIGNATOR	DESCRIPTION	SYMBOL	DESCRIPTION
	Type of DC/DC Converter	A	3-pin DC/DC converter with built-in switching transistor
		C	Stand-by capability with built-in switching transistor
	Output Voltage	Integer	e.g. $V_{OUT}=3.5V$ =3, =5
	Oscillation Frequency	0	50kHz
		1	100kHz
		2	180kHz
	Packages Taping Type ^(*)	PR	SOT-89 (XC6371/72 A type)
			SOT-89-5 (XC6371/72 C type)
		DR	USP-6B

^(*) The device orientation is fixed in its embossed tape pocket.

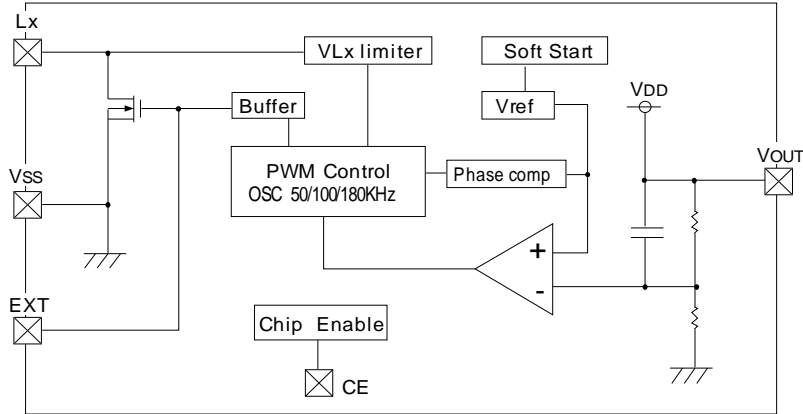
For reverse orientation, please contact your local Torex sales office or representative.

(Standard orientation: R, Reverse orientation: L)

BLOCK DIAGRAMS

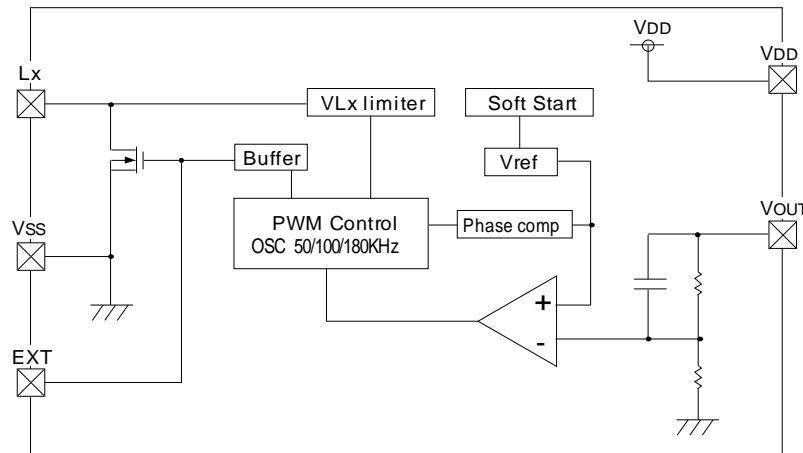
XC6371/XC6372A, C

(The VOUT pin serves also as VDD)



Note: The CE pin is only used with the XC6371C.

XC6371/72/73E



Note: Built-in transistor type units use the Lx pin.

ABSOLUTE MAXIMUM RATINGS

Ta=25

PARAMETER	SYMBOL	RATINGS	UNITS
Vout Input Voltage	Vout	12	V
Lx pin Voltage	VLX	12	V
Lx pin Current	ILX	400	mA
CE Input Voltage	VCE	12	V
Power Dissipation	Pd	SOT-89, SOT-89-5	500
		USP-6B	100
			mW
VDD Input Voltage	VDD	12	V
Operating Temperature Range	Topr	-30~ + 80	
Storage Temperature Range	Tstg	-40~ + 125	

ELECTRICAL CHARACTERISTICS

XC6371/72A501

V_{OUT}=5.0V, FOSC=100kHz

T_a=25

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	V _{OUT}		4.875	5.000	5.125	V
Maximum Input Voltage	V _{IN}		10	-	-	V
Operation Start Voltage	V _{ST1}	External Components Connected, I _{OUT} =1mA	-	-	0.90	V
Oscillation Start Voltage	V _{ST2}	No external components. Apply voltage to V _{OUT} Lx : 10k pull-up to 5V	-	-	0.80	V
No Load Input Current	I _{IN}	V _{IN} =V _{OUT} × 0.8, I _{OUT} =0mA ^(*)	-	12.8	25.7	μA
Supply Current 1	I _{DD1}	Same as V _{ST2} , Apply output voltage × 0.95 to V _{OUT}	-	80.2	133.8	μA
Supply Current 2	I _{DD2}	Same as V _{ST2} , Apply output voltage × 1.1 to V _{OUT}	-	8.2	16.5	μA
Lx Switch-On Resistance	R _{SWON}	Same as I _{DD1} , V _{LX} =0.4V	-	1.4	2.4	
Lx Leak Current	I _{LXL}	No external components. V _{OUT} =V _{LX} =10V	-	-	1.0	μA
Oscillation Frequency	FOSC	Same as I _{DD1} . Measuring of Lx waveform	85	100	115	kHz
Maximum Duty Ratio	MAXDTY	Same as I _{DD1} . Measuring of Lx waveform	80	87	92	%
PFM Duty Ratio ^(*)	PFMDTY	Same as I _{DD1} . Measuring of Lx waveform	10	17	25	%
Lx Limit Voltage	V _{LXLMT}	Same as I _{DD1} . Apply output voltage to Lx, Voltage required to produce FOSC × 2	0.7	-	1.3	V
Efficiency	EFFI		-	85	-	%
Slow-Start Time	T _{SS}		4.0	10.0	20.0	ms

NOTE: Unless otherwise stated, V_{IN}=V_{OUT} × 0.6, I_{OUT}=50mA. See Typical Application Circuits, Circuit1

*1: The Schottky diode (SD) must be type MA735, with reverse current (I_R)<1.0 μA at reverse voltage (V_R)=10.0V.(XC6372A)

*2: "Supply Current 1" is the supply current while the oscillator is continuously oscillating. In actual operation the oscillator periodically operates which results in less average power consumption. The current actually provided by an external V_{IN} source is represented by "No Load Input Current (I_{IN})".

*3: When PWM operates at PWM Mode.

*4: When PFM operates at PFM Mode.(XC6372A)

ELECTRICAL CHARACTERISTICS (Continued)

XC6371/72C501

V_{OUT}=5.0V, FOSC=100kHz

T_a=25

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Output Voltage	V _{OUT}		4.875	5.000	5.125	V
Maximum Input Voltage	V _{IN}		10	-	-	V
Operation Start Voltage	V _{ST1}	External Components Connected, I _{OUT} =1mA	-	-	0.90	V
Operation Start Voltage	V _{ST2}	No external components. Apply voltage to V _{OUT} , Lx : 10k pull-up to 5V	-	-	0.80	V
No Load Input Current	I _{IN}	V _{IN} =V _{OUT} × 0.8, I _{OUT} =0mA ^(*1)	-	12.8	25.7	μA
Supply Current 1	I _{DD1}	Same as V _{ST2} , Apply output voltage × 0.95 to V _{OUT}	-	80.2	133.8	μA
Supply Current 2	I _{DD2}	Same as V _{ST2} , Apply output voltage × 1.1 to V _{OUT}	-	8.2	16.5	μA
Lx Switch-On Resistance	R _{SWON}	Same as I _{DD1} , V _{Lx} =0.4V	-	1.4	2.4	
Lx Leak Current	I _{LXL}	No external components, V _{OUT} =V _{Lx} =10V	-	-	1.0	μA
Oscillation Frequency	FOSC	Same as I _{DD1} , Measuring of Lx waveform	85	100	115	KHZ
Maximum Duty Ratio	MAXDTY	Same as I _{DD1} , Measuring of Lx waveform	80	87	92	%
PFM Duty Ratio ^(*4)	PFMDTY	Same as I _{DD1} , Measuring of Lx waveform	10	17	25	%
Stand-by Current	I _{STB}	Same as I _{DD1}	-	-	0.5	μA
CE "High" Voltage	V _{CEH}	Same as I _{DD1} , Lx Oscillation start	0.75	-	-	V
CE "Low" Voltage	V _{CEL}	Same as I _{DD1} , Lx Oscillation stop	-	-	0.20	V
CE "High" Current	I _{CEH}	Same as I _{DD1} , V _{CE} =V _{OUT} × 0.95	-	-	0.25	μA
CE "Low" Current	I _{CEL}	Same as I _{DD1} , V _{CE} =0V	-	-	-0.25	μA
Lx Limit Voltage	V _{LxLMT}	Same as I _{DD1} , Apply output voltage to Lx, Voltage required to produce FOSC × 2	0.7	-	1.3	V
Efficiency	EFFI		-	85	-	%
Slow-Start Time	T _{SS}		4.0	10.0	20.0	ms

NOTE: Unless otherwise stated, connect CE to V_{OUT}, V_{IN}=V_{OUT} × 0.6, I_{OUT}=50mA. See Typical Application Circuits, Circuit 2.

*1: The Schottky diode (SD) must be type MA735, with reverse current (I_R)<1.0 μA at reverse voltage (V_R)=10.0V.(XC6372C)

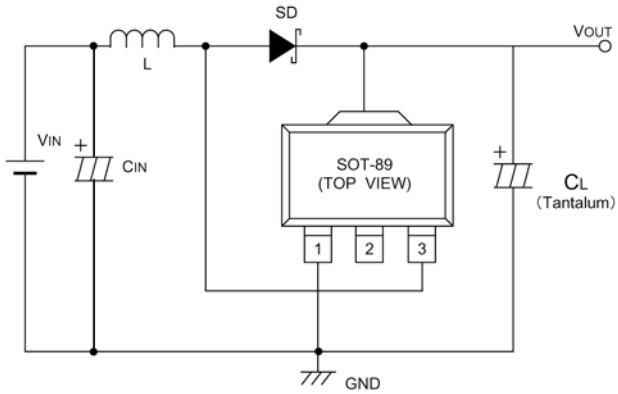
*2: "Supply Current 1" is the supply current while the oscillator is continuously oscillating. In actual operation the oscillator periodically operates which results in less average power consumption. The current actually provided by an external V_{IN} source is represented by "No Load Input Current (I_{IN})".

*3: When PWM operates at PWM Mode.

*4: When PFM operates at PFM Mode.(XC6372C)

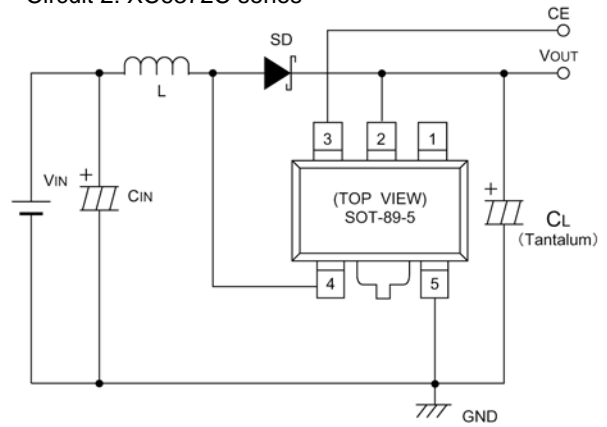
TYPICAL APPRICATION CIRCUITS

Circuit 1: XC6372A series



- L : 100 μ H (SUMIDA, CR54)
- SD : MA2Q735 (Schottky diode; MATSUSHITA)
- CL : 16V 47 μ F (Tantalum capacitor, NICHICHEMI MCE)
- CIN : 16V 220 μ F (Aluminium Electrolytic Capacitor)

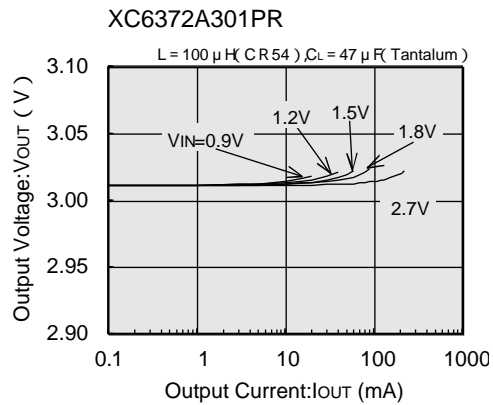
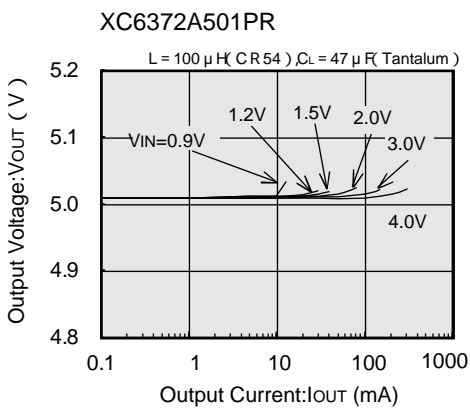
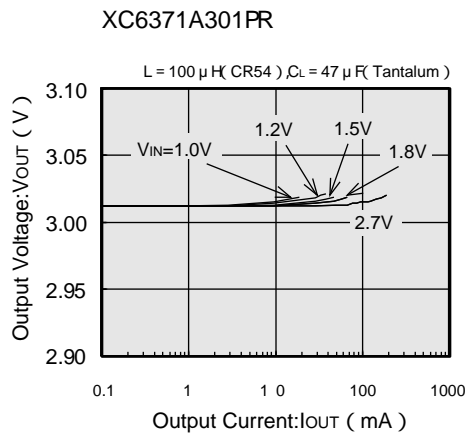
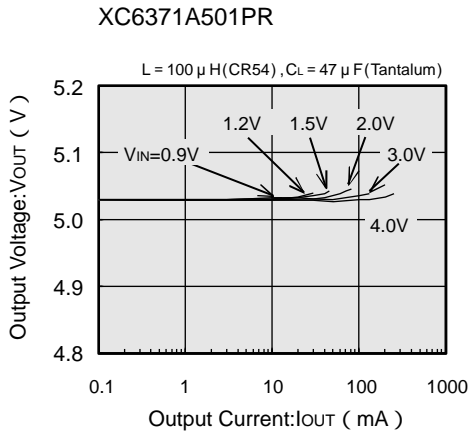
Circuit 2: XC6372C series



- L : 100 μ H (CR54, SUMIDA)
- SD : MA2Q735 (Schottky Diode; MATUSHITA)
- CL : 16V 47 μ F (Tantalum Capacitor, NICHICHEMI MCE)
- CIN : 16V 220 μ F (Aluminium Electrolytic Capacitor)

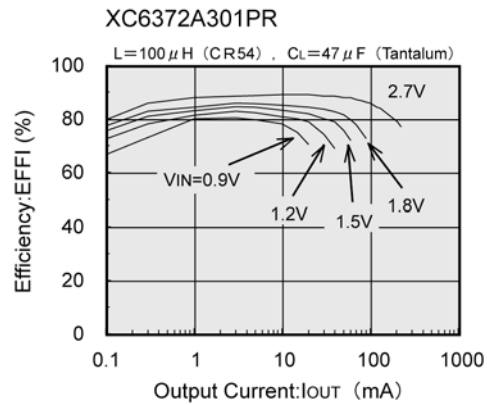
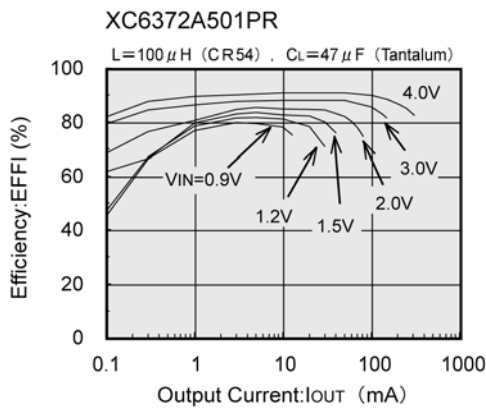
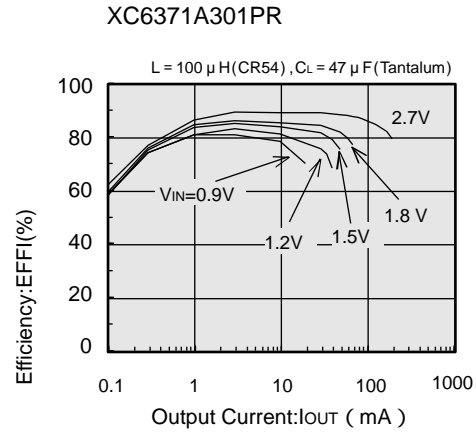
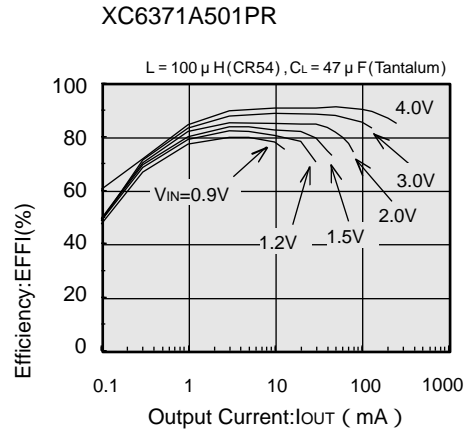
TYPICAL PERFORMANCE CHARACTERISTICS

(1) Output Voltage vs. Output Current



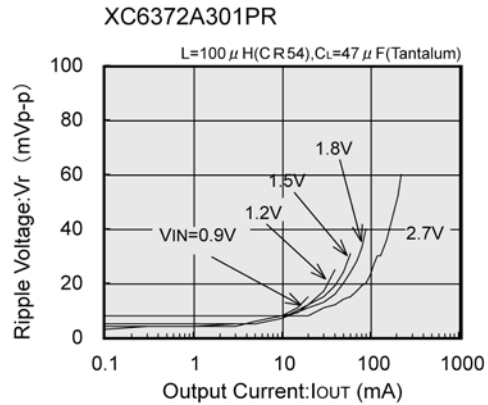
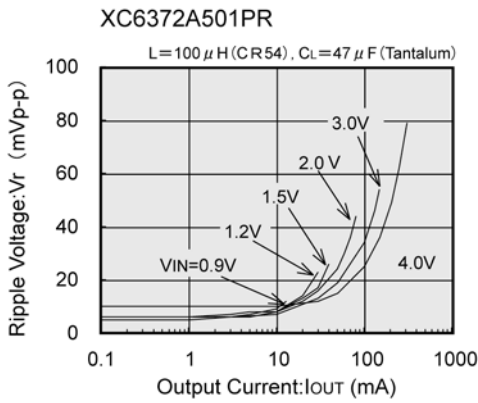
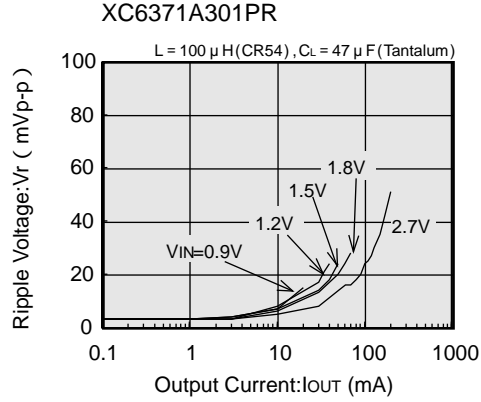
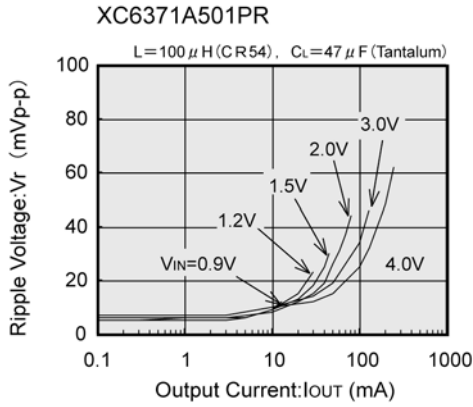
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(2) Efficiency vs. Output Current



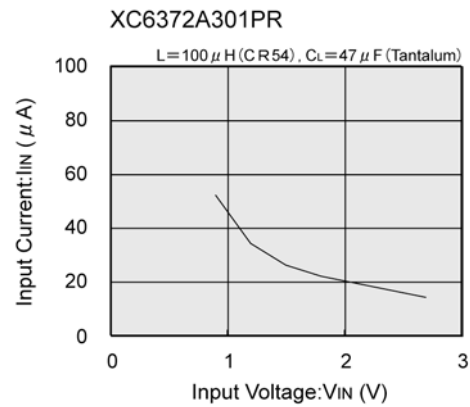
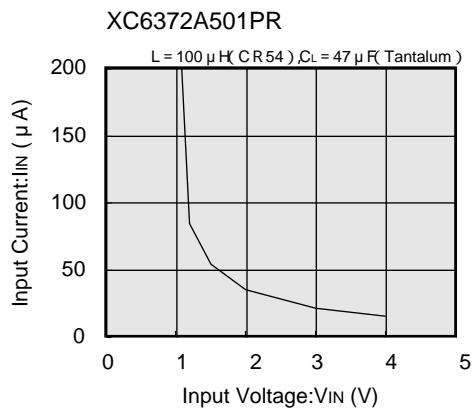
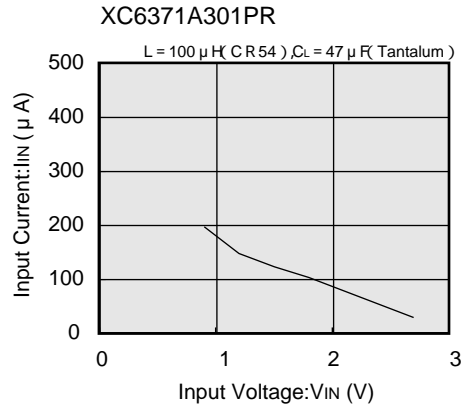
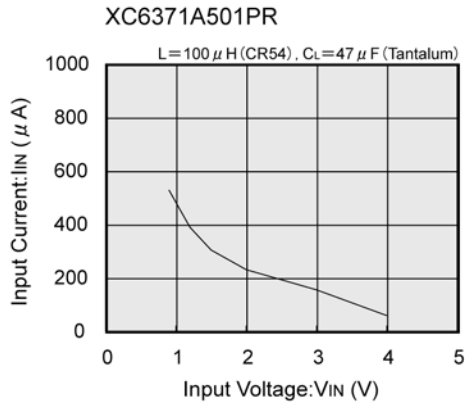
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(3) Ripple Voltage vs. Output Current



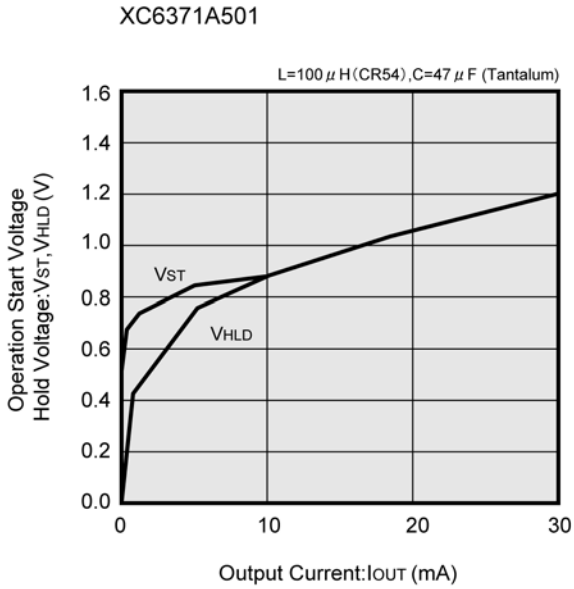
TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(4) No Load Input Current vs. Input Voltage

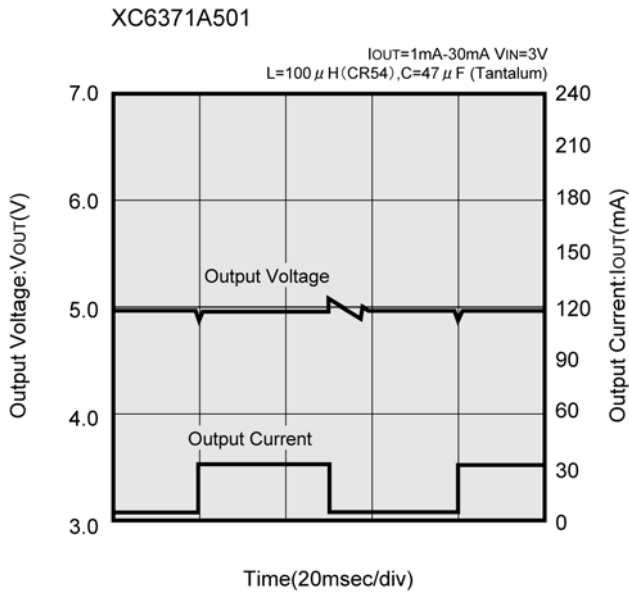


TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

(5) Operation Start Voltage / Hold Voltage vs. Output Current

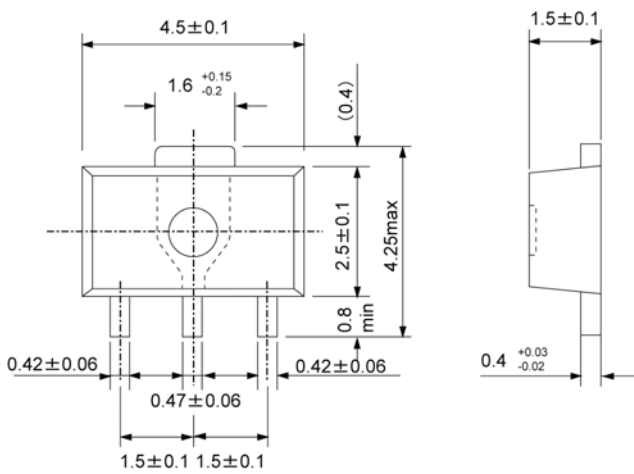


(6) Load Transient Response

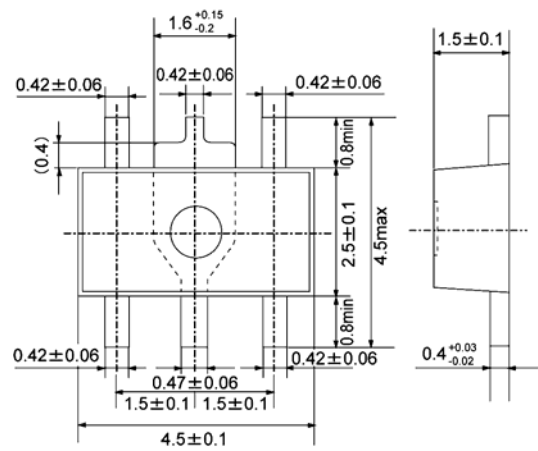


PACKAGING INFORMATION

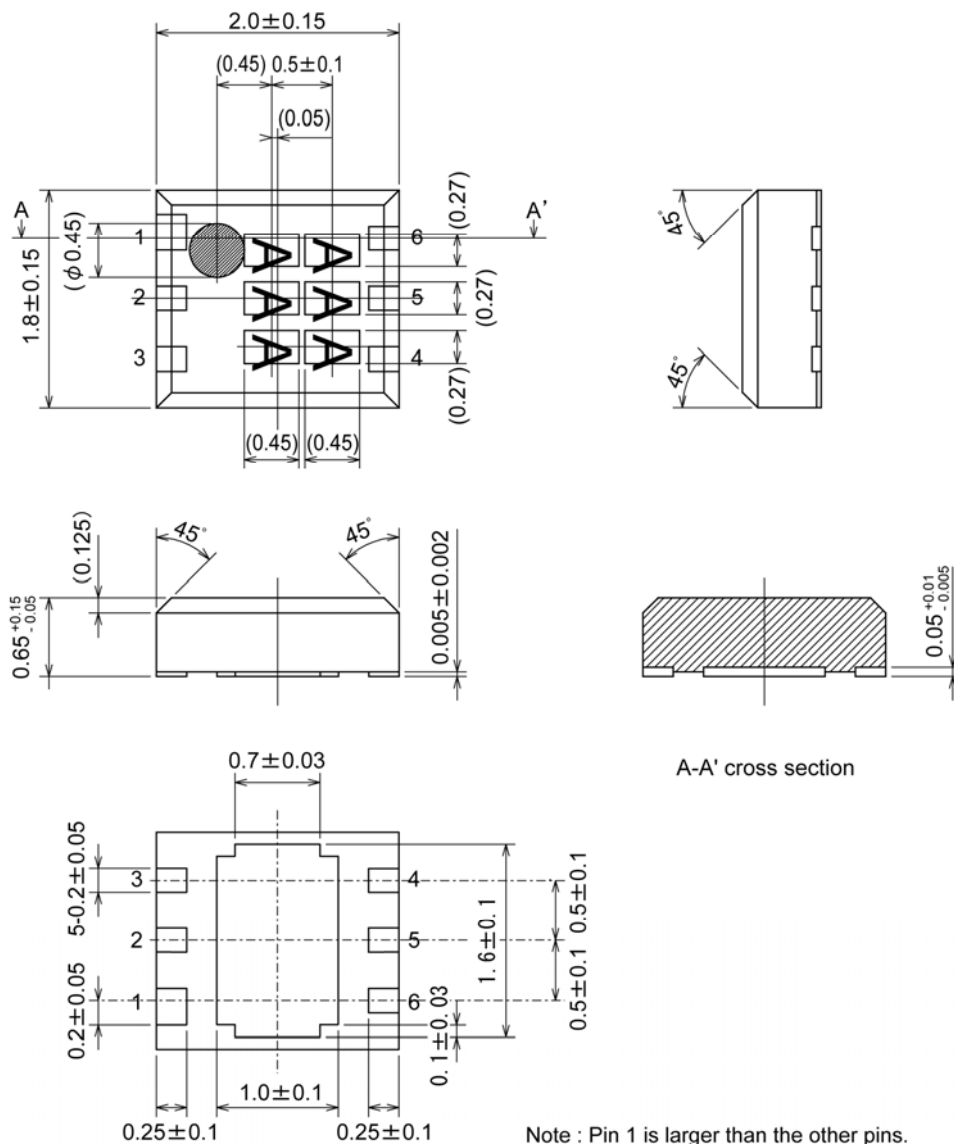
SOT-89



SOT-89-5

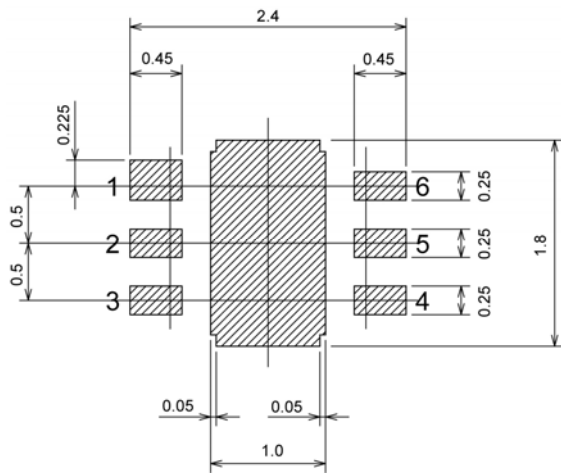


USP-6B

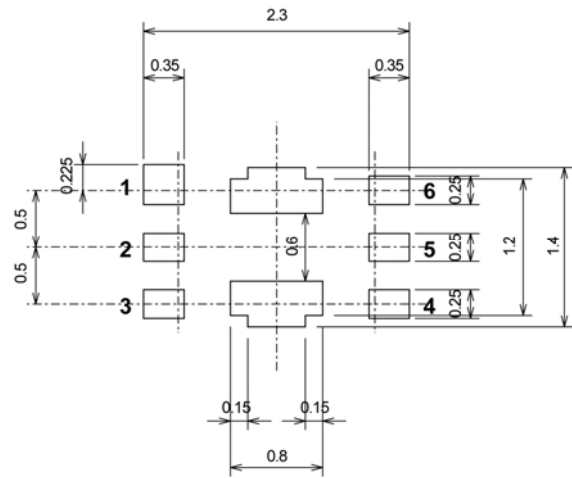


PACKAGING INFORMATION (Continued)

USP-6B Recommended Pattern Layout



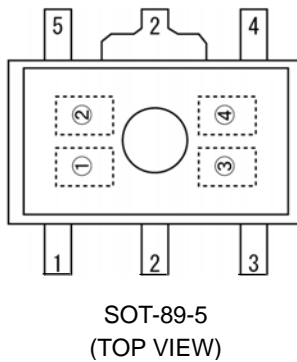
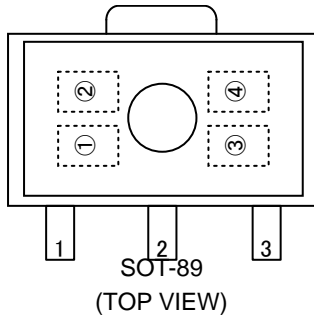
USP-6B Recommended Metal Mask Design



MARKING RULE

[XC6371/XC6372]

SOT-89, SOT-89-5



Represents product series

MARK	PRODUCT SERIES
A	XC6371A
A	XC6371C

MARK	PRODUCT SERIES
1	XC6372A
1	XC6372C

Represents integer of output voltage and oscillation frequency

OUTPUT VOLTAGE (V)	OSCILLATION FREQUENCY		
	50kHz	100kHz	180kHz
1.x	B	1	1
2.x	C	2	2
3.x	F	3	3
4.x	E	4	4
5.x	F	5	5
6.x	H	6	6
7.x	K	7	7

Represents decimal number of output voltage and oscillation frequency

OUTPUT VOLTAGE (V)	OSCILLATION FREQUENCY		
	50kHz	100kHz	180kHz
x.0	0	0	A
x.1	1	1	B
x.2	2	2	C
x.3	3	3	D
x.4	4	4	E
x.5	5	5	F
x.6	6	6	H
x.7	7	7	K
x.8	8	8	L
x.9	9	9	M

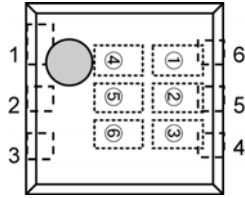
Represents production lot number

0 to 9, A to Z repeated (G, I, J, O, Q, W excepted).

MARKING RULE (Continued)

[XC6371/XC6372] (Continued)

USP-6B



USP-6B
(TOP VIEW)

Represents product series

MARK	PRODUCT SERIES
5	XC6371xxxxDx
2	XC6372xxxxDx

Represents product classification

MARK	PRODUCT SERIES
A	XC6371A
C	XC6371C

Represents output voltage (ex.)

MARK		OUTPUT VOLTAGE (V)
3	3	
5	0	5.0

Represents oscillation frequency

MARK	OSCILLATION FREQUENCY (kHz)
0	50
1	100
2	180

Represents production lot number

0 to 9, A to Z repeated (G, I, J, O, Q, W excepted)

Note: No character inversion used.

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